

DUAL HIGH SPEED SINGLE SUPPLY OPERATIONAL AMPLIFIER

■FEATURES

- High Slew Rate 10V/μs
- High Bandwidth 3MHz
- High Unity Gain Frequency 3.6MHz
- Input Offset Voltage 5.5mV max.
- Single Supply 3V~36V
- Operating Temperature Range -40°C~+125°C
- Low input voltage around GND level
- Unity-Gain Stable
- Operating Current (All amplifiers) 4mA
- No Phase Reversal
- High EMI Immunity
- Output Short-Circuit Protection
- Package

NJM3472 SOP8, SSOP8, VSP8

■GENERAL DESCRIPTION

The NJM3472 is a dual high speed single supply operational amplifier with operation voltage range from 3V to 36V and operation temperature range from -40 to 125°C.

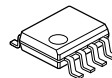
10V/μs slew rate and 3MHz gain bandwidth is suitable for inverter and active filter.

Compared with the TL3472, the characteristics of low-power are improved.

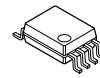
■APPLICATIONS

- Current Sensor
- Buffer Application Amplifier
- Active filter
- Battery Application

■PACKAGE OUTLINE



**NJM3472G
(SOP8)**

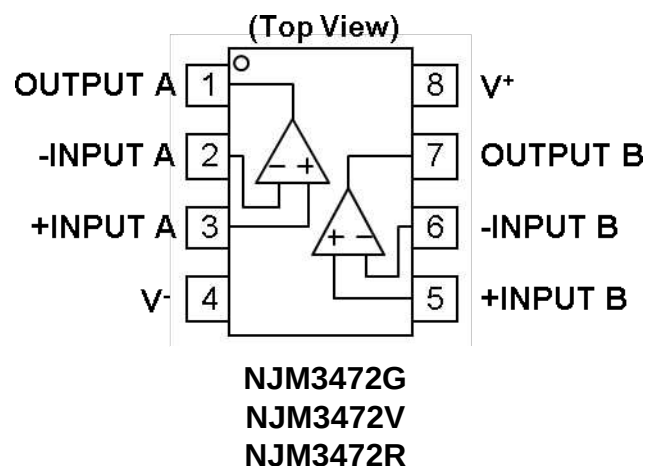


**NJM3472V
(SSOP8)**



**NJM3472R
(VSP8)**

■PIN CONFIGURATION



■ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise noted.)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V^+ - V^-$	40 ⁽⁵⁾	V
Differential Input Voltage ⁽¹⁾	V_{ID}	± 40 ⁽²⁾	V
Input Voltage ⁽²⁾	V_{IN}	$V^- - 0.3$ to $V^- + 40$	V
Output Terminal Input Voltage	V_O	$V^- - 0.3$ to $V^+ + 0.3V$	V
Power Dissipation ⁽³⁾	P_D	(2-layer / 4-layer)	mW
SOP8		780 / 1200	
SSOP8		510 / 650	
VSP8		600 / 810	
Output Short-Circuit Duration ⁽⁴⁾		infinite	
Operating Temperature Range	T_{opr}	-40 to +125	°C
Storage Temperature Range	T_{stg}	-55 to +150	°C

(1) Differential voltage is the voltage difference between +INPUT and -INPUT.

(2) Input voltage should be allowed to apply to the input terminal independent of the magnitude of V^+ . The normal operation will establish when any input is within the Common Mode Voltage Range of electrical characteristics.

(3) Power dissipation is the power that can be consumed by the IC at Ta=25°C, and is the typical measured value based on JEDEC condition. When using the IC over Ta=25°C subtract the value $[mW/°C]=P_D/(T_{stg}(MAX)-25)$ per temperature.

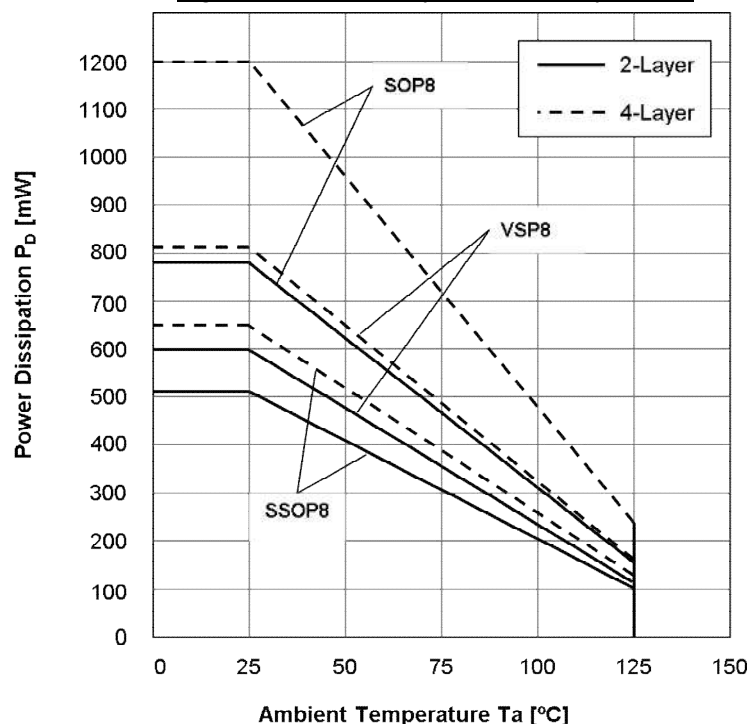
2-layer: EIA/JEDEC STANDARD Test board (76.2x114.3x1.6mm, 2layers, FR-4) mounting

4-layer: EIA/JEDEC STANDARD Test board (76.2x114.3x1.6mm, 4layers, FR-4) mounting

(4) Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.

(5) Supply Voltage is the voltage difference between V^+ and V^- .

Figure1. Power Dissipation vs. Temperature


■RECOMMENDED OPERATING CONDITIONS (Ta=25°C)

PARAMETER	Supply Voltage	UNIT
Supply Voltage	+3 to +36 (± 1.5 to ± 18)	V

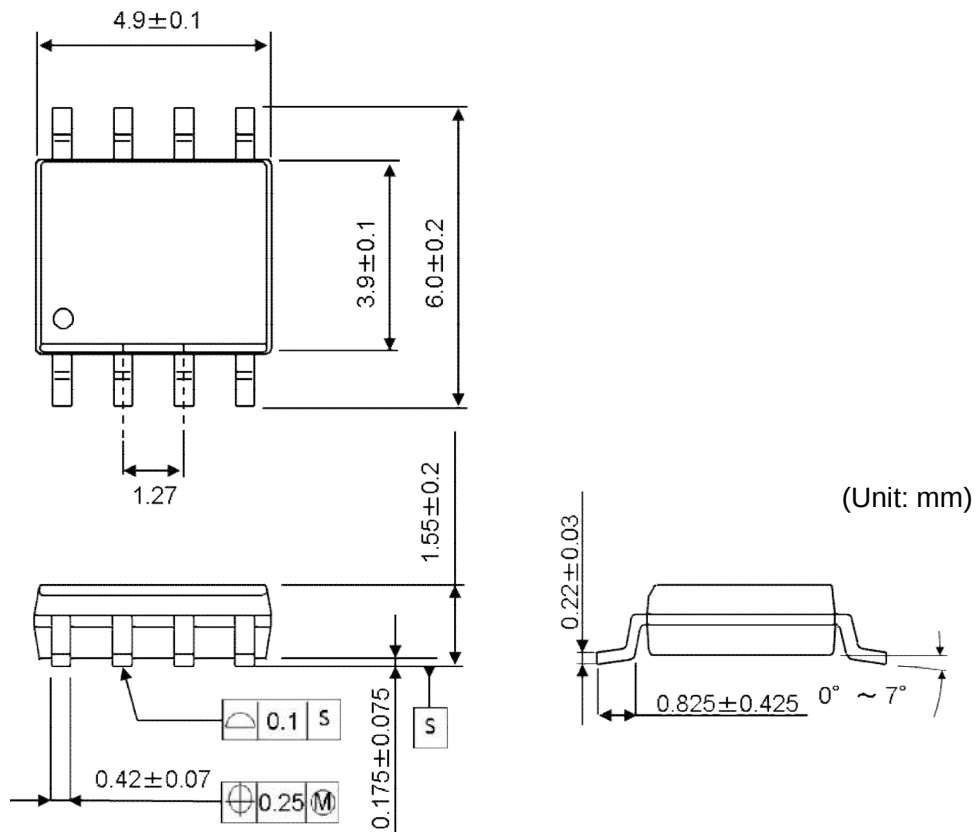
■ELECTRICAL CHARACTERISTICS ($V^+=+15V$, $V^-=-15V$, $V_{CM}=0V$, $T_a=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
INPUT CHARACTERISTICS						
Input Offset Voltage	V _{IO}	R _S =50Ω, V _{CM} =0V	-	1	5.5	mV
Input Offset Voltage Drift	ΔV _{IO} /ΔT	T _a =-40°C~+125°C	-	10	-	μV/°C
Input Bias Current	I _B		-	80	150	nA
Input Offset Current	I _{IO}		-	5	75	nA
Open-Loop Voltage Gain	A _V	V _O =±10V, R _L =2kΩ to 0V	80	95	-	dB
Common Mode Rejection Ratio	CMR	V _{ICM} =-15V to 13.0V	60	100	-	dB
Common Mode Input Voltage Range	V _{ICM}	CMR≥60dB	V ⁻	-	V ⁺ -2.0	V
OUTPUT CHARACTERISTICS						
High-level Output Voltage	V _{OH}	R _L =10kΩ to 0V	13.7	14	-	V
		R _L =2kΩ to 0V	13.5	13.8	-	
Low-level Output Voltage	V _{OL}	R _L =10kΩ to 0V	-	-14.8	-14.3	V
		R _L =2kΩ to 0V	-	-13.8	-13.5	
Output Source Current	I _{SOURCE}	V _O =0V, +Input=+1V, -Input=0V	10	35	-	mA
Output Sink Current	I _{SINK}	V _O =0V, +Input=0V, -Input=+1V	20	60	-	mA
POWER SUPPLY						
Supply Current (All amplifiers)	I _{SUPPLY}	No Signal, R _L =∞	-	4	5	mA
Supply Voltage Rejection Ratio	SVR	V ⁺ /V ⁻ =±2V to ±18V, V _{ICM} =0V	60	95	-	dB
AC CHARACTERISTICS						
Gain Bandwidth Product	GBW	R _L =2kΩ to 0V, f=100kHz	-	3	-	MHz
Unity Gain Frequency	f _T	R _L =2kΩ to 0V	-	3.6	-	MHz
Slew Rate	SR	G _V =0dB, R _L =2kΩ to 0V, C _L =20pF, V _{in} =-10V to +10V	7.5	10	-	V/μs
Full Power Bandwidth	FPBW	G _V =0dB, R _L =2kΩ to 0V, C _L =20pF, V _O =20V _{pp} , THD=5.0%	-	190	-	kHz
Settling Time	t _s	G _V =0dB, 10V step To 0.1%	-	1.8	-	μs
		G _V =0dB, 10V step To 0.01%	-	12	-	
Phase Margin	φ _M	R _L =2kΩ to 0V, C _L =20pF	-	78	-	deg
		R _L =2kΩ to 0V, C _L =220pF	-	68	-	
Gain Margin	GM	R _L =2kΩ to 0V, C _L =20pF	-	12	-	dB
		R _L =2kΩ to 0V, C _L =220pF	-	6	-	
NOISE, THD						
Equivalent Input Noise Voltage	e _n	f=1kHz	-	48	-	nV/√Hz
Total Harmonic Distortion + Noise	THD+N	G _V =20dB, R _L =2kΩ to 0V, C _L =20pF, f=10kHz, V _O =20V _{pp}	-	0.02	-	%
Channel Separation	CS	f=1kHz, Equivalent Input value	-	120	-	dB

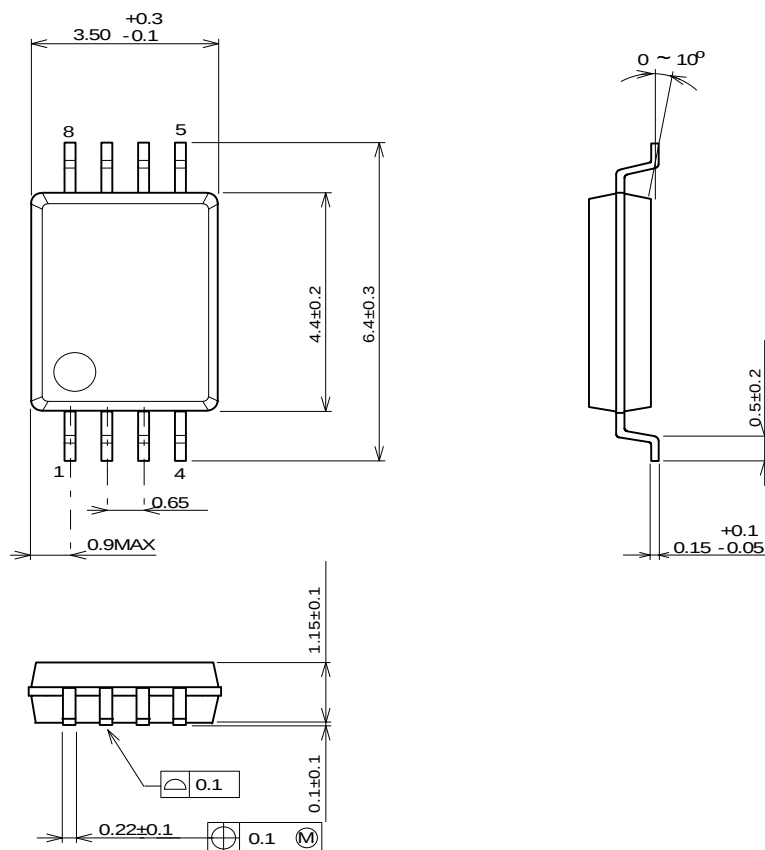
■ELECTRICAL CHARACTERISTICS ($V^+=+5V$, $V^-=0V$, $V_{CM}=2.5V$, $T_a=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
INPUT CHARACTERISTICS						
Input Offset Voltage	V_{IO}	$R_S=50\Omega$, $V_{CM}=0V$, $V_O=V^+/2$	-	1	5.5	mV
Input Offset Voltage Drift	$\Delta V_{IO}/\Delta T$	$T_a=-40^\circ C \sim +125^\circ C$	-	10	-	$\mu V/^\circ C$
Input Bias Current	I_B	$V_{CM}=V^+/2$, $V_O=V^+/2$	-	80	150	nA
Input Offset Current	I_{IO}	$V_{CM}=V^+/2$, $V_O=V^+/2$	-	5	75	nA
Open-Loop Voltage Gain	A_V	$V_O=1.5V$ to $3.5V$, $R_L=2k\Omega$ to $V^+/2$	80	95	-	dB
Common Mode Rejection Ratio	CMR	$V_{CM}=0V$ to $3V$	60	90	-	dB
Common Mode Input Voltage Range	V_{ICM}	CMR ≥ 60 dB	V^-	-	$V^+-2.0$	V
OUTPUT CHARACTERISTICS						
High-level Output Voltage	V_{OH}	$R_L=2k\Omega$ to $0V$	3.7	4	-	V
Low-level Output Voltage	V_{OL}	$R_L=2k\Omega$ to $0V$	-	0.1	0.3	V
Output Source Current	I_{SOURCE}	$V_O=0V$	10	28	-	mA
Output Sink Current	I_{SINK}	$V_O=5V$	20	60	-	mA
POWER SUPPLY						
Supply Current (All amplifier)	I_{SUPPLY}	No Signal, $R_L=\infty$	-	3.3	4.5	mA
AC CHARACTERISTICS						
Gain Bandwidth Product	GBW	$R_L=2k\Omega$ to $0V$, $f=100kHz$	-	3	-	MHz
Unity Gain Frequency	f_T	$R_L=2k\Omega$ to $0V$	-	3.2	-	MHz
Slew Rate	SR	$G_V=0dB$, $R_L=2k\Omega$ to $0V$, $C_L=20pF$, $V_{in}=+2V$ to $+3V$	5	7	-	V/ μs
Phase Margin	ϕ_M	$R_L=2k\Omega$ to $0V$, $C_L=20pF$	-	64	-	deg
Gain Margin	GM	$R_L=2k\Omega$ to $0V$, $C_L=20pF$	-	13	-	dB
NOISE, THD						
Equivalent Input Noise Voltage	e_n	$f=1kHz$	-	48	-	$nV/\sqrt{Hz}$
Total Harmonic Distortion + Noise	THD+N	$G_V=6dB$, $R_L=2k\Omega$ to $0V$, $C_L=20pF$, $f=1kHz$, $V_O=2V_{pp}$	-	0.01	-	%
Channel Separation	CS	$f=1kHz$, Equivalent Input value	-	120	-	dB

■ PACKAGE DIMENSIONS

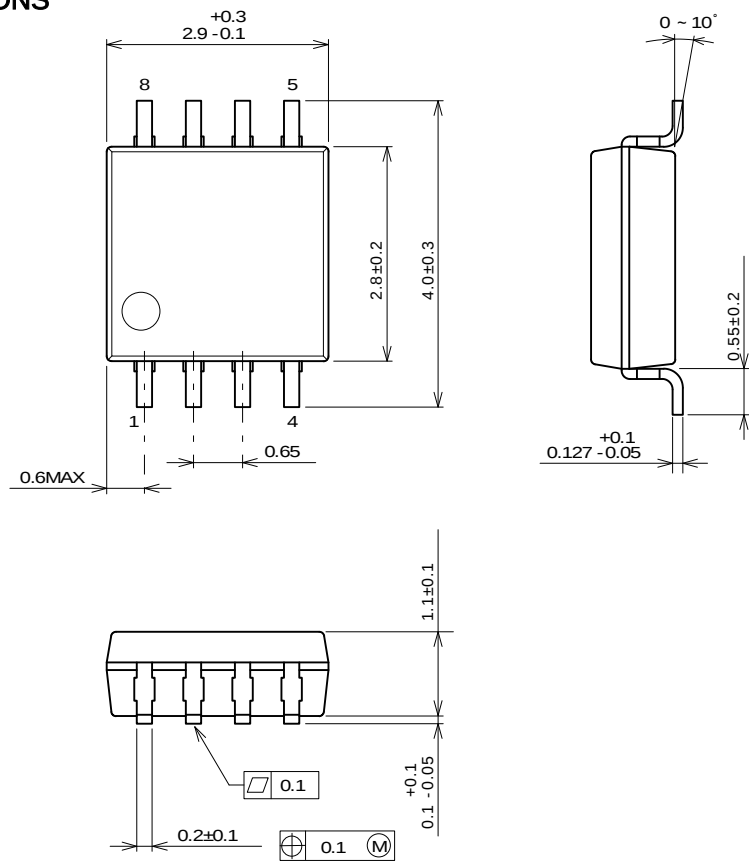


SOP8 Package



SSOP8 Package

■ PACKAGE DIMENSIONS



(Unit: mm)

MSOP8 (TVSP8) JEDEC MO-187-DA / thin type Package

[CAUTION]

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- Поставка образцов и прототипов;
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- Защита от снятия компонента с производства.



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